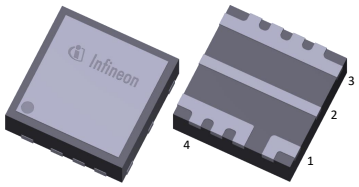
CoolGaN™

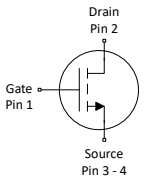
PG-TSON-4

CoolGaN™ Transistor 100 V G3



Features

- Ultra fast switching and high efficiency
- Space saving and highly robust package
- No reverse recovery charge
- Ultra low gate charge and output charge
- Exposed die for top-side thermal excellence
- Moisture rating MSL1
- Industrial grade 3x3 package



Top side is exposed silicon substrate, internally connected to source terminal. Not recommended to use as an electrical connection.

Potential applications

- Telecom & Datacenter 48V IBC
- Sync Rectification for AC-DC and DC-DC converters
- Robotics and drones
- Battery powered tools
- 48V servo drive
- e-Mobility, UAVs
- Class D Audio
- Solar & Energy storage systems
- Point of Load Converters

GaN Hal

Pb RoHS

Product validation

Qualified for industrial applications according to the relevant tests of JEDEC JESD47, JESD22 and J-STD-020.

Table 1 Key performance parameters

Parameter	Value	Unit
V_{DS}	100	V
$R_{DS(on)}$	5.0	mΩ
I_D	38	A
Q_{oss}	25	nC
Q_G	6.1	nC
Q_{rr}	0	nC

Part number	Package	Marking	Related links
IGB070S10S1	PG-TSON-4	AA1	see Appendix A

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1 Maximum ratings

at T_j = 25 °C, unless otherwise specified. Stresses beyond max ratings may cause permanent damage to the device. For optimum lifetime and reliability, Infineon recommends operating conditions that do not continuously exceed 80 % of the maximum ratings stated (unless otherwise explicitly stated). For further information, contact your local Infineon sales office.

Table 2 Maximum ratings

Parameter	Symbol	Values			Unit	Note / Test condition
		Min.	Typ.	Max.		
Continuous drain-source voltage	V_{DS}	-	-	100	V	V_{GS}=0 V
Pulsed drain-source voltage [1]	$V_{DS,\ pulse}$	-	-	120	V	V_{GS}=0 V, 1 h total time
Continuous drain current	I_D	-	-	38	A	V_{GS}=5 V, T_C=25 °C
				13		V_{GS}=5 V, T_A=25 °C, R_{thJA}=48 °C/W [2]
Pulsed drain current [3]	$I_{D,pulse}$	-	-	360	A	T_j=25 °C
				170		T_j=150 °C
Pulsed gate-source voltage [1]	V_{GS}	-6.5	-	6.5	V	Pulsed 100 h total time
Power dissipation	P_{tot}	-	-	23	W	T_C=25 °C
				2.6		T_A=25 °C, R_{thJA}=48 °C/W [2]
Storage temperature	T_{stg}	-55	-	150	°C	-
Junction temperature	T_j	-40				

[1] Provided as measure of robustness under abnormal operating conditions and not recommended for normal operation.

[2] Device on 4-layer FR4 PCB, vertical in still air.

[3] Pulse current limited by transfer characteristic.

2 Recommended operating conditions

Table 3 Recommended operating conditions

Parameter	Symbol	Values			Unit	Note / Test condition
		Min.	Typ.	Max.		
Gate-source voltage	V_{GS}	-4.0	5.0	5.5	V	-

3 Thermal characteristics

Table 4 Thermal characteristics

Parameter	Symbol	Values			Unit	Note / Test condition
		Min.	Typ.	Max.		
Thermal resistance, junction - case, top	R_{thJC}	-	1.1	1.3	°C/W	-
Thermal resistance, junction - case, bottom			3.7	5.4		
Thermal resistance, junction - ambient 1s0p	R_{thJA}	-	68	-	°C/W	On 1 layer PCB, vertical in still air.
Thermal resistance, junction - ambient 2s2p	R_{thJA}	-	48	-	°C/W	With vias on 4 layer PCB, vertical in still air.

4 Electrical Characteristics

at T_j=25 °C, unless otherwise specified

Table 5 Static characteristics

Parameter	Symbol	Values			Unit	Note / Test condition
		Min.	Typ.	Max.		
Gate threshold voltage	$V_{GS(th)}$	1.2	2.1	2.9	V	V_{DS}=V_{GS}, I_D=4.5 mA
Drain-source leakage current	I_{DSS}	-	0.2	1.0	µA	V_{DS}=100 V, V_{GS}=0 V, T_j=25 °C
			3.0	25		V_{DS}=100 V, V_{GS}=0 V, T_j=125 °C
Gate-source leakage current	I_{GSS}	-	11	140	µA	V_{GS}=5 V, T_j=25 °C
			0.01	0.1		V_{GS}=-4 V, T_j=25 °C
			70	640		V_{GS}=5 V, T_j=125 °C
			0.01	0.1		V_{GS}=-4 V, T_j=125 °C
Drain-source on-state resistance	$R_{DS(on)}$	-	5.0	7.0	mΩ	V_{GS}=5 V, I_D=13 A
Gate resistance [4)]	R_G	-	0.5	-	Ω	-

4) Defined by design. Not subject to production test.

Table 6 Capacitance characteristics [5)]

Parameter	Symbol	Values			Unit	Note / Test condition
		Min.	Typ.	Max.		
Input capacitance	C_{iss}	-	650	740	pF	V_{GS}=0 V, V_{DS}=50 V, f=1 MHz
Output capacitance	C_{oss}		310	340		
Reverse transfer capacitance	C_{rss}		3.6	4.7		

5) Defined by design. Not subject to production test.

Table 7 Gate charge characteristics

Parameter	Symbol	Values			Unit	Note / Test condition
		Min.	Typ.	Max.		
Gate to source charge	Q_{gs}	-	1.8	-	nC	V_{DS}=50 V, I_D=13 A, V_{GS}=0 to 5 V
Gate charge at threshold	$Q_{g(th)}$		1.3	-	nC	
Gate to drain charge [6)]	Q_{gd}		1.7	-	nC	
Switching charge	Q_{sw}		2.2	-	nC	
Gate charge total [6)]	Q_g		6.1	7.9	nC	
Gate plateau voltage	$V_{plateau}$		2.8	-	V	
Output charge [6)]	Q_{oss}	-	25	28	nC	V_{DS}=50 V, V_{GS}=0 V

6) Defined by design. Not subject to production test.

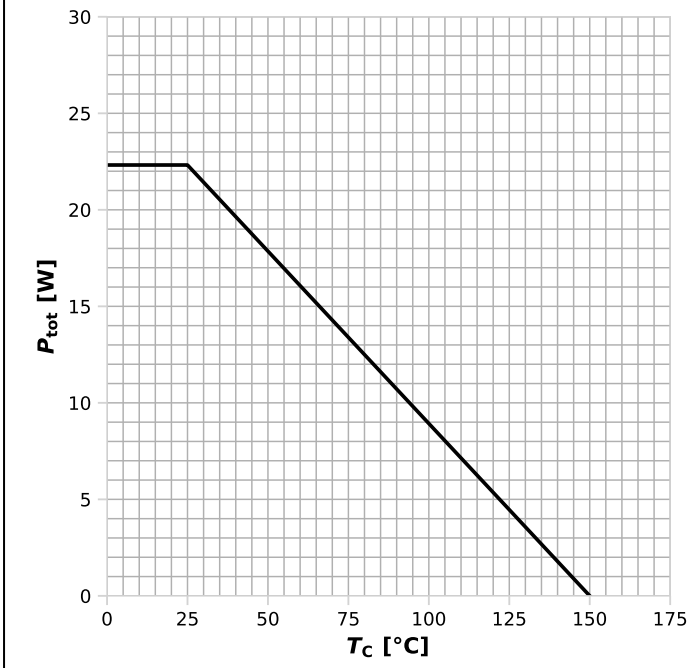
Table 8 Reverse operation

Parameter	Symbol	Values			Unit	Note / Test condition
		Min.	Typ.	Max.		
Reverse continuous current	I_S	-	-	7.4	A	T_C=25 °C
Pulsed current, reverse	$I_{S,pulse}$			152		
Source-Drain reverse voltage	V_{SD}	-	2.7	3.5	V	V_{GS}=0 V, $I_{S,pulse}$=13 A, T_j=25 °C
			2.3	-		V_{GS}=0 V, $I_{S,pulse}$=0.5 A, T_j=25 °C
Reverse recovery charge [7)]	Q_{rr}	-	0	-	nC	V_R=50 V, $I_{S,pulse}$=13 A, d$i_{S,pulse}$/dt =100 A/µs

7) Defined by design. Not subject to production test.

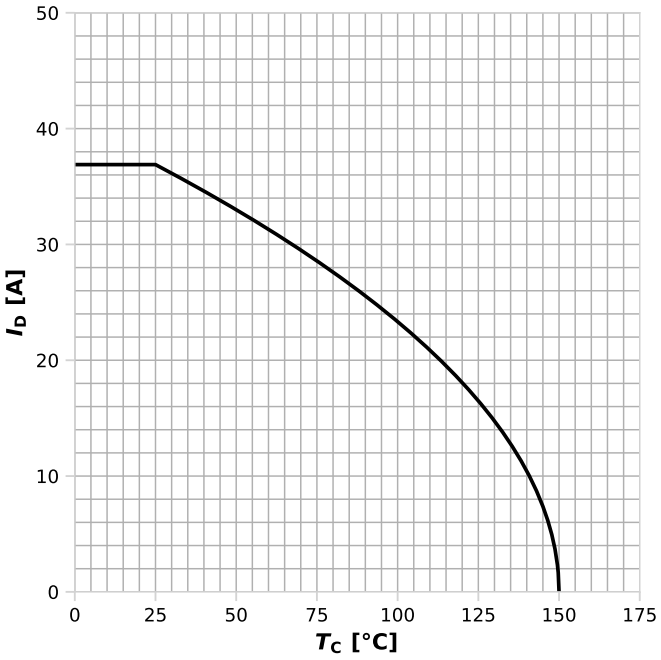
5 Electrical characteristics diagrams

Diagram 1: Power dissipation



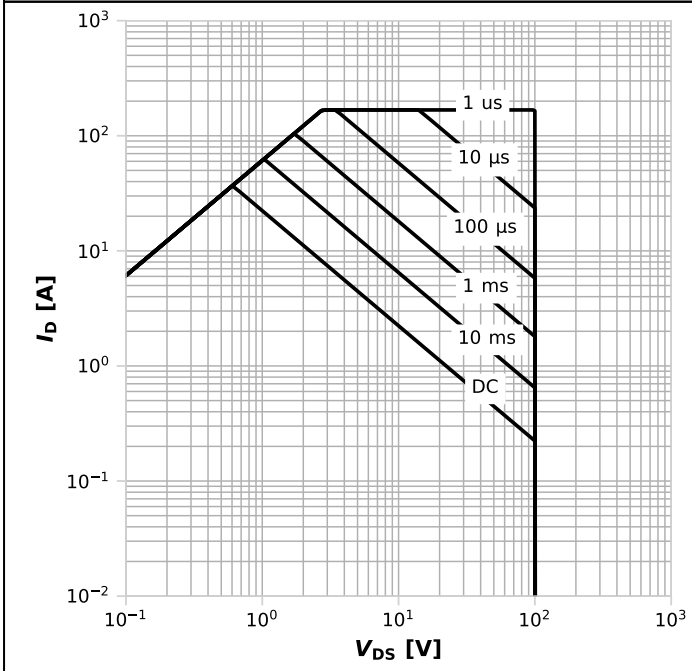
P_{tot}=f(T_C)

Diagram 2: Drain Current



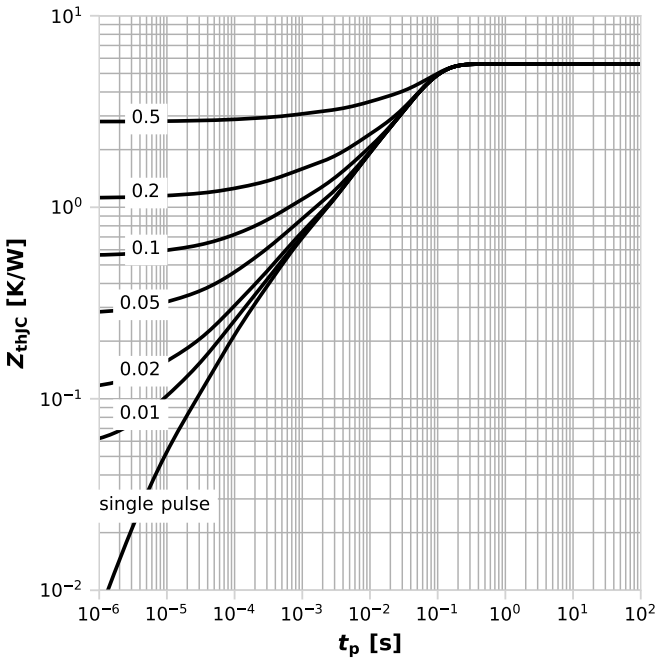
I_D=f(T_C)

Diagram 3: Safe operating area



I_D=f(V_{DS}); T_C=25 °C; D=0; parameter: t_p

Diagram 4: Max. transient thermal impedance



Z_{thJC} =f(t_P); parameter: D=t_p/T

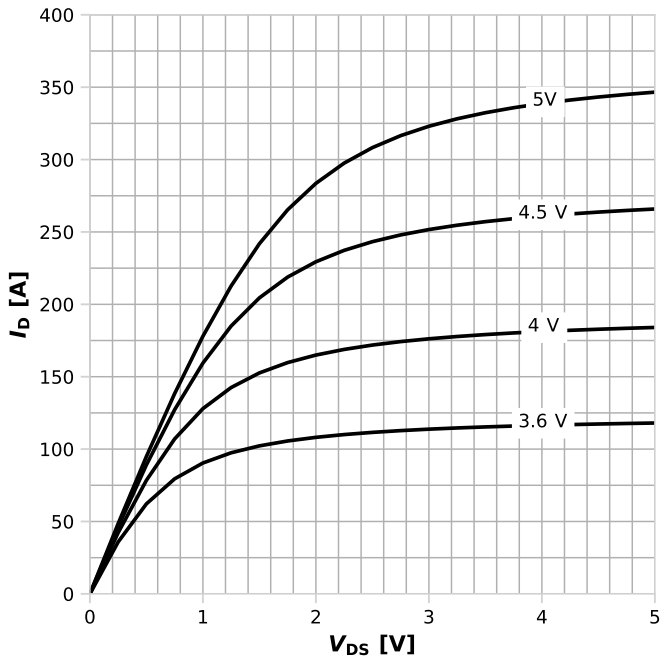
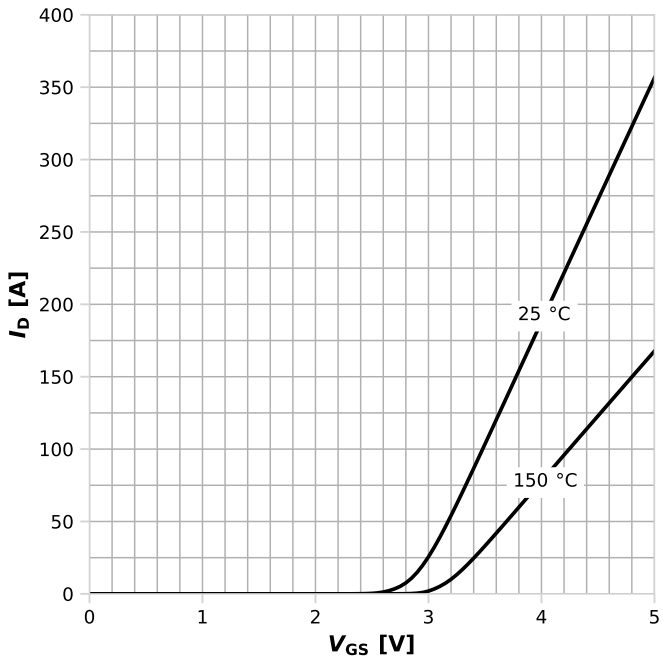
Diagram 5: Typ. output characteristics	Diagram 6: Typ. transfer characteristics
	
I_D=f(V_{DS}); T_j=25 °C; parameter: V_{GS}	I_D=f(V_{GS}); |V_{DS}|>2|I_D|$R_{DS(on)max}$; parameter: T_j

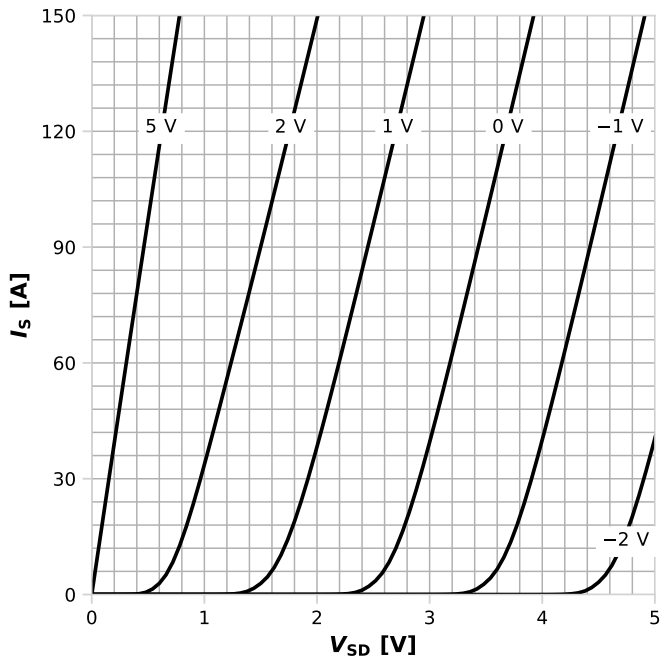
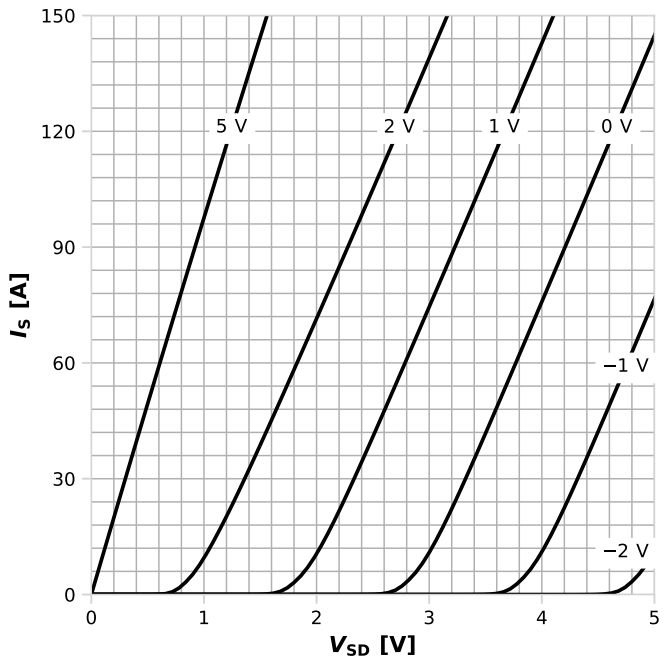
Diagram 7: Typ. channel reverse characteristics	Diagram 8: Typ. channel reverse characteristics
	
I_S=f(V_{SD}); T_j=25 °C; parameter: V_{GS}	I_S=f(V_{SD}); T_j=125 °C; parameter: V_{GS}

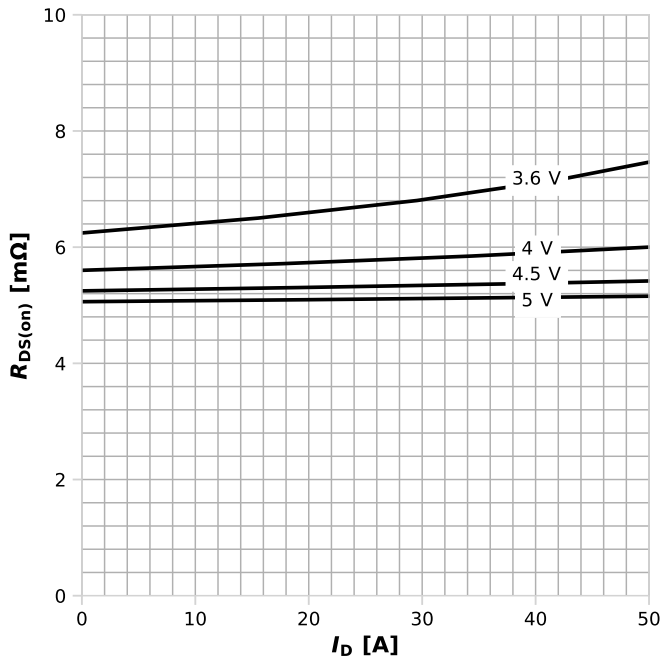
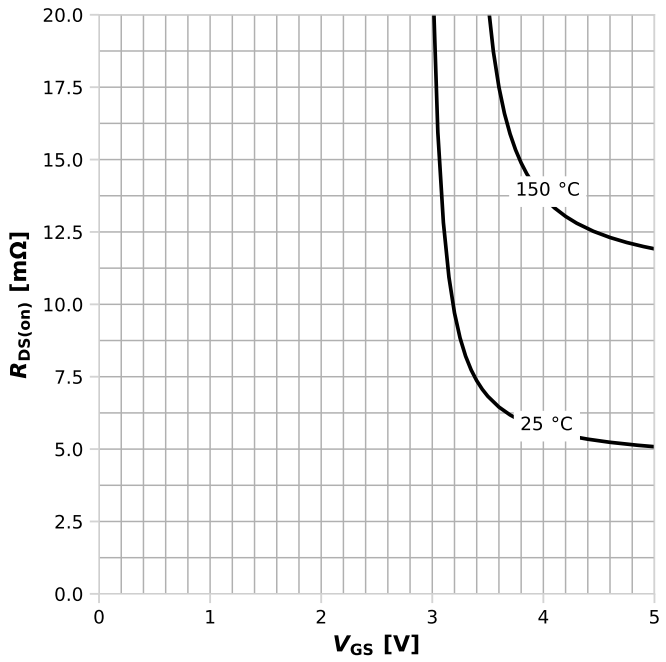
Diagram 9: Typ. drain-source on-state resistance	Diagram 10: Typ. Drain-source on-state resistance
	
$R_{DS(on)}$=f(I_D); T_j=25 °C; parameter: V_{GS}	$R_{DS(on)}$=f(V_{GS}); I_D=13 A; parameter: T_j

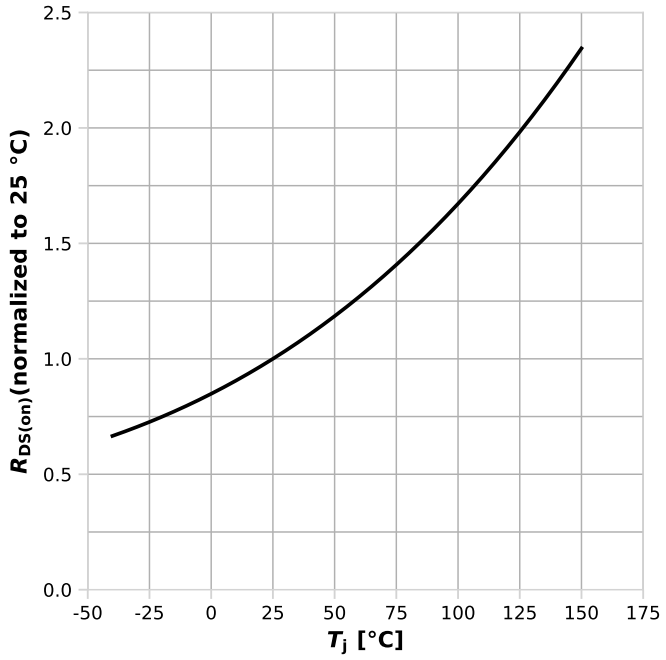
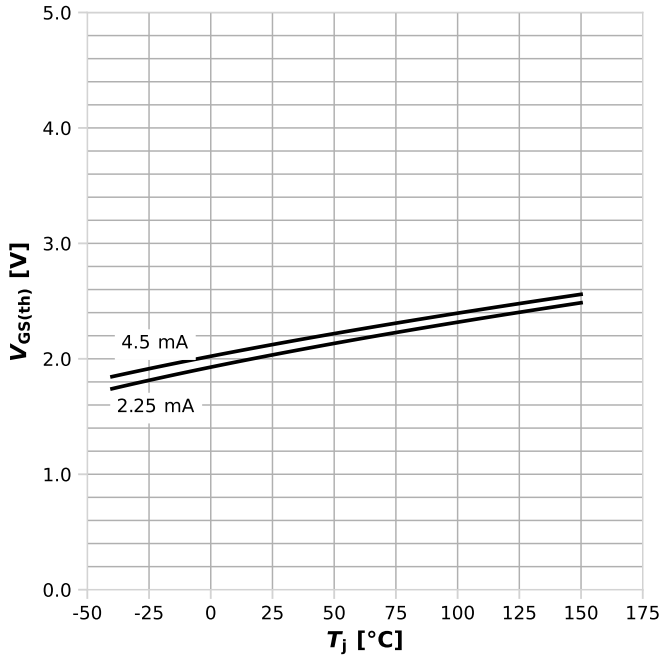
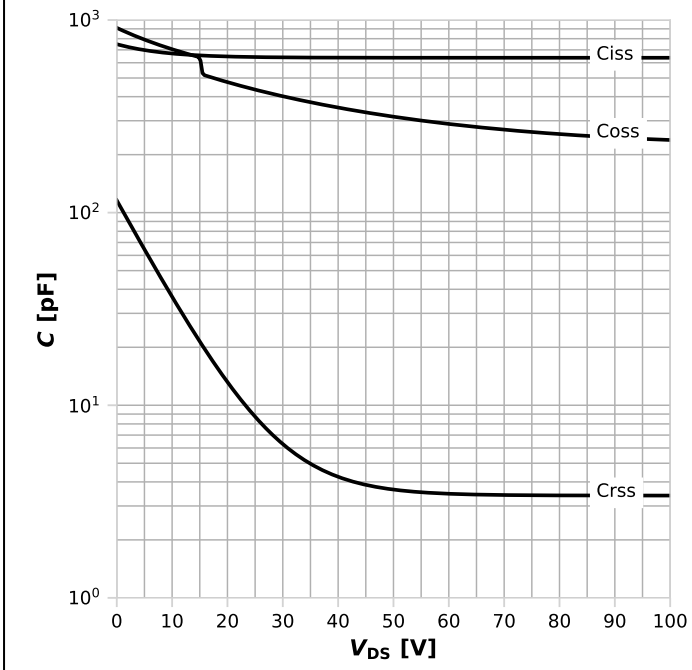
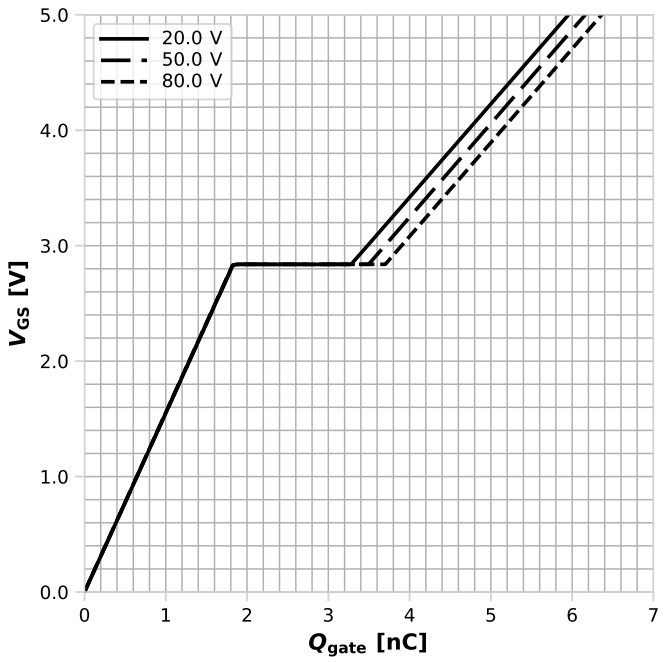
Diagram 11: Drain-source on-state resistance	Diagram 12: Typ. gate threshold voltage
	
$R_{DS(on)}$=f(T_j); I_D=13 A, V_{GS}=5V	$V_{GS(th}$=f(T_j), V_{GS}=V_{DS}; parameter: I_D

Diagram 13: Typ. capacitances



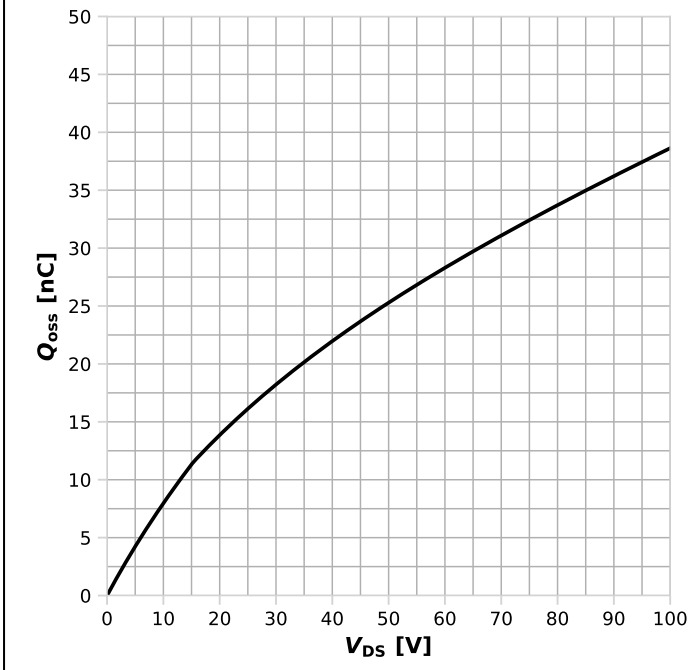
C=f(V_{DS}); V_{GS}=0 V

Diagram 14 Typ. gate charge



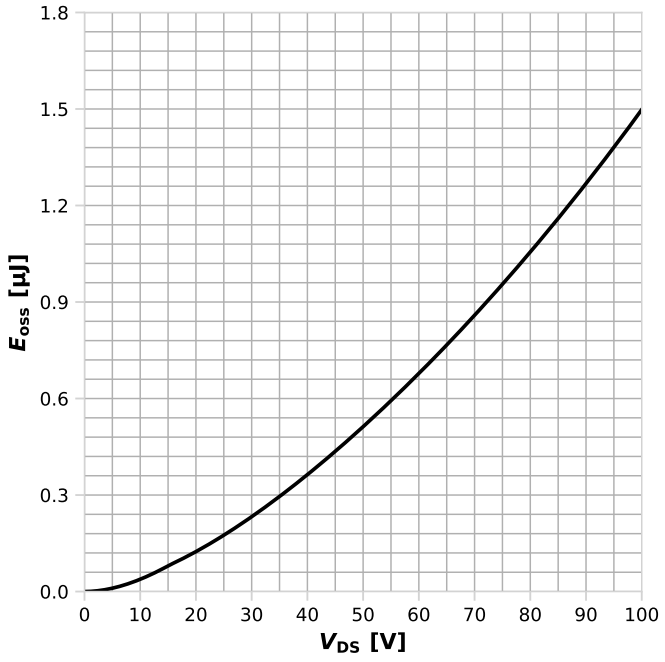
V_{GS}=f(Q_{gate}); I_D=13 A pulsed; parameter: V_{DS}

Diagram 15: Typ. output charge



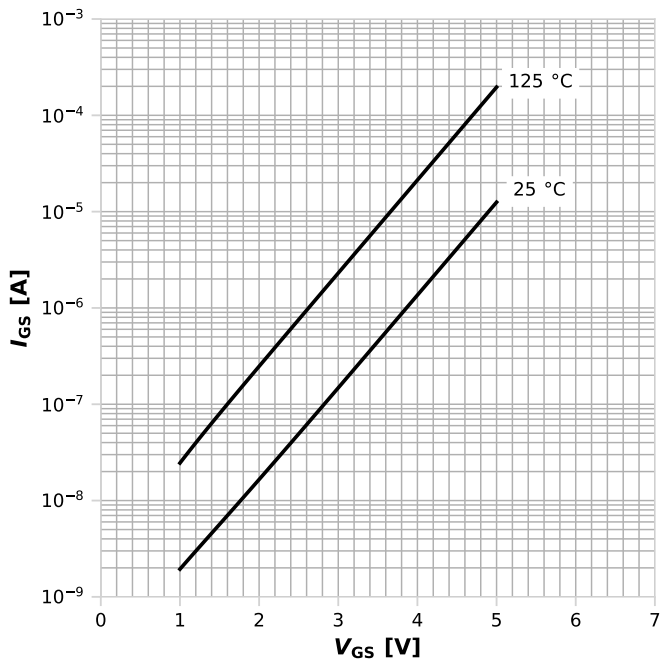
Q_{oss}=f(V_{DS}), V_{GS}=0 V

Diagram 16: Typ. Coss stored Energy



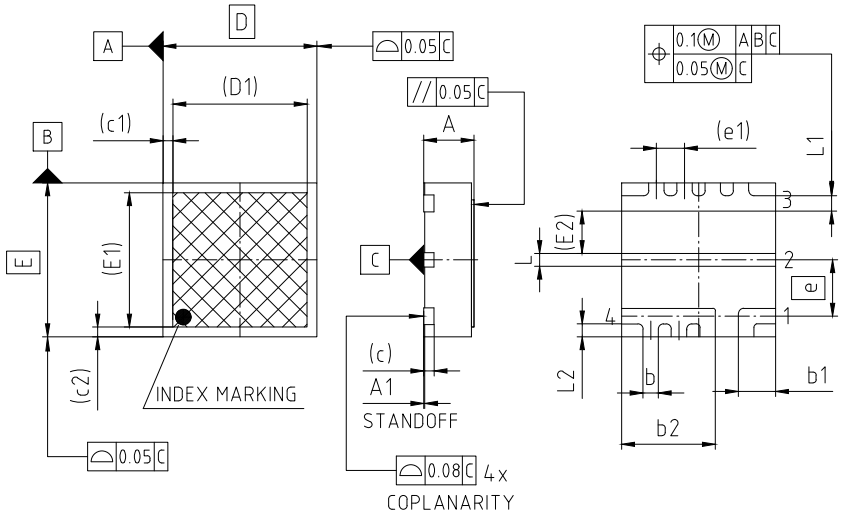
E_{oss}=f(V_{DS}), V_{GS}=0 V

Diagram 17: Typ. gate characteristics forward



I_{GS}=f(V_{GS}); V_{DS}=0 V; parameter: T_j

6 Package outlines



PACKAGE - GROUP NUMBER:	PG-TSON-4-U02	
DIMENSIONS	MILLIMETERS	
	MIN.	MAX.
A	0.832	1.032
A1	---	0.05
b	0.20	0.40
b1	0.625	0.825
b2	1.725	1.925
c	0.20	
c1	0.192	
c2	0.192	
D	3.00	
D1	2.62	
E	3.00	
E1	2.62	
E2	0.825	
L	0.20	0.30
L1	0.25	0.35
L2	0.20	0.30
e	1.10	
e1	0.55	

NOTE: DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURRS

Figure 1 Outline PG-TSON-4, dimensions in mm

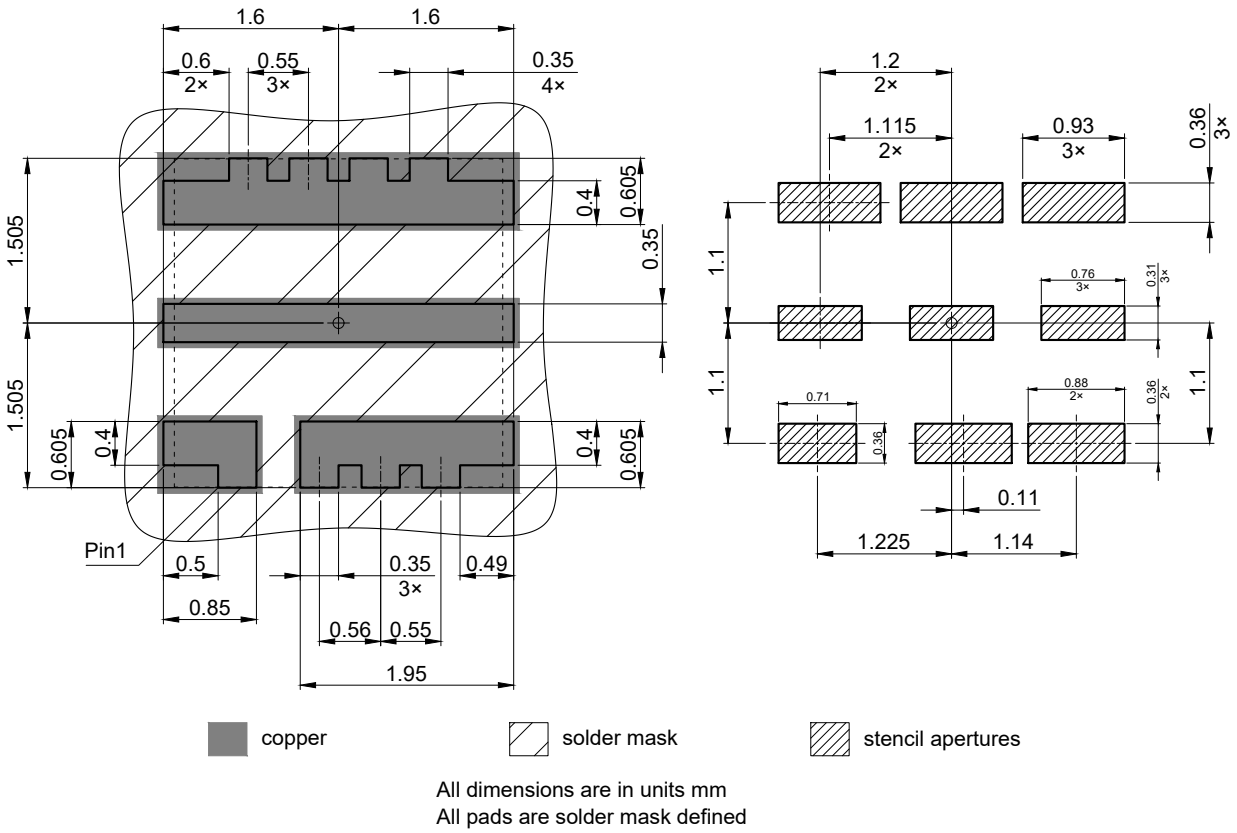


Figure 2 Footprint drawing PG-TSON-4, dimensions in mm

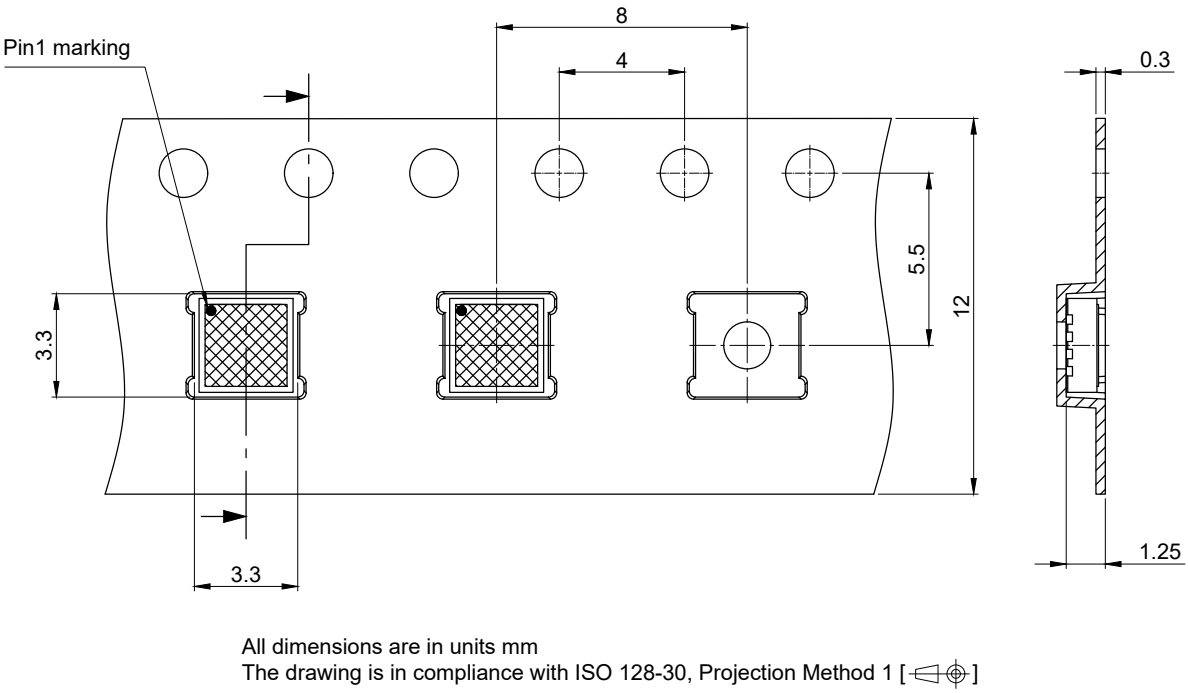


Figure 3 Packaging variant PG-TSON-4, dimensions in mm

7 Appendix A

Table 9 Related links

- IFX CoolGaN™ GaN webpage
- IFX CoolGaN™ reliability white paper
- IFX CoolGaN™ gate driver application note
- IFX CoolGaN™ Evaluation Boards
- IFX Packages Description-PG-TSON-4-3

Revision history

IGB070S10S1

Revision 2025-04-22, Rev. 1.1

Previous revisions

Revision	Date	Subjects (major changes since last revision)
1.0	2025-01-27	Release of final version
1.1	2025-04-22	Updated static IGSS characteristics

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